

## Quad high side smart power solid state relay

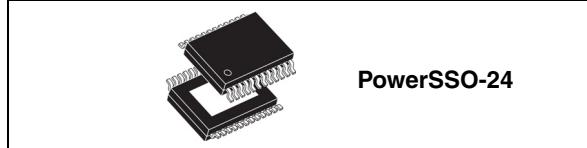
Datasheet –production data

### Features

Type	$V_{demag}^{(1)}$	$R_{DSon}^{(1)}$	$I_{out}^{(1)}$	$V_{cc}$
VNI4140K-32	$V_{CC}$ -41 V	0.08 Ω	1 A	41 V

1. Per channel

- Output current: 1 A per channel
- Shorted load protections
- Junction overtemperature protection
- Case overtemperature protection for thermal independence of the channels
- Thermal case shutdown restart not simultaneous for the various channels
- Protection against loss of ground
- Current limitation
- Undervoltage shutdown
- Open drain diagnostic outputs
- 3.3 V CMOS/TTL compatible inputs
- Fast demagnetization of inductive loads
- Conforms to IEC 61131-2
- ESD according to IEC 61000-4-2 up to +/- 25 KV

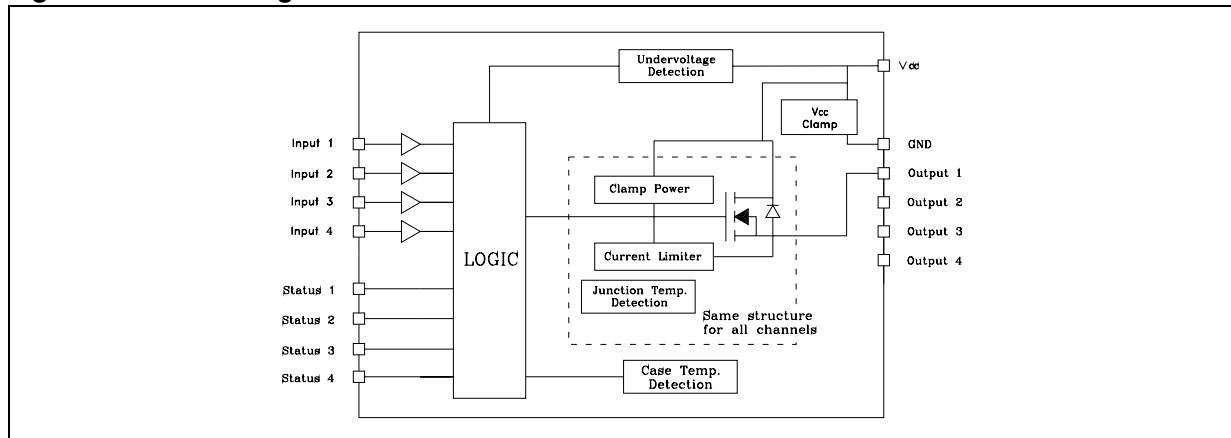


PowerSSO-24

### Description

The VNI4140K-32 is a monolithic device made using STMicroelectronics VIPower technology, intended for driving four independent resistive, capacitive or inductive loads with one side connected to ground. Active current limitation avoids the system power supply dropping in the case of shorted load. Built-in thermal shutdown protects the chip from overtemperature and short-circuit. In overload condition, the channel turns OFF and back ON automatically so as to maintain junction temperature between  $T_{TSD}$  and  $T_R$ . If this condition causes case temperature to reach  $T_{CSD}$ , the overloaded channel is turned OFF and restarts only when case temperature has decreased down to  $T_{CR}$ . In the case of more than one channel in overload, re-start of the overloaded channels is not simultaneous, in order to avoid high peak current from the supply. Non-overloaded channels continue to operate normally. The open drain diagnostic outputs indicate overtemperature conditions.

**Figure 1. Block diagram**

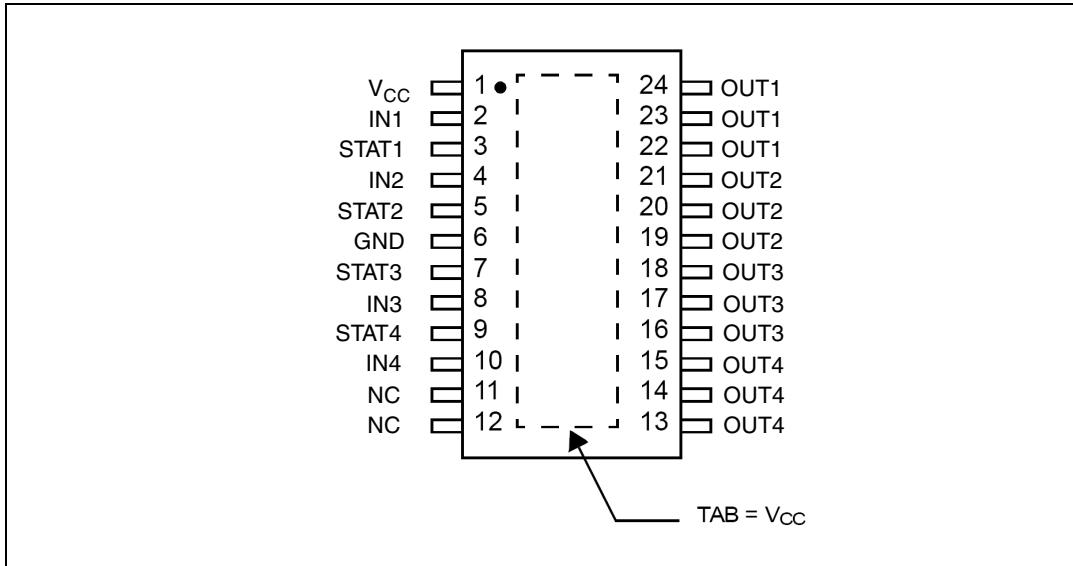


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# 1 Pin connection

**Figure 2.** Pin connection (top view)



**Table 1.** Pin description

Pin	Name	Description
Tab	TAB	Exposed tab internally connected to Vcc
1	Vcc	Supply voltage
2	IN1	Channel 1 input 3.3 V CMOS/TTL compatible
3	STAT1	Channel 1 status in open drain configuration
4	IN2	Channel 2 input 3.3 V CMOS/TTL compatible
5	STAT2	Channel 2 status in open drain configuration
6	GND	Device ground connection
7	STAT3	Channel 3 status in open drain configuration
8	IN3	Channel 3 input 3.3 V CMOS/TTL compatible
9	STAT4	Channel 4 status in open drain configuration
10	IN4	Channel 4 input 3.3 V CMOS/TTL compatible
11	NC	
12	NC	
13	OUT4	Channel 4 power stage output, internally protected
14	OUT4	Channel 4 power stage output, internally protected
15	OUT4	Channel 4 power stage output, internally protected
16	OUT3	Channel 3 power stage output, internally protected
17	OUT3	Channel 3 power stage output, internally protected

**Table 1. Pin description (continued)**

Pin	Name	Description
18	OUT3	Channel 3 power stage output, internally protected
19	OUT2	Channel 2 power stage output, internally protected
20	OUT2	Channel 2 power stage output, internally protected
21	OUT2	Channel 2 power stage output, internally protected
22	OUT1	Channel 1 power stage output, internally protected
23	OUT1	Channel 1 power stage output, internally protected
24	OUT1	Channel 1 power stage output, internally protected

## 2 Maximum ratings

**Table 2. Absolute maximum rating**

Symbol	Parameter	Value	Unit
$V_{CC}$	Power supply voltage	41	V
$-V_{CC}$	Reverse supply voltage	-0.3	V
$I_{GND}$	DC ground reverse current	-250	mA
$I_{OUT}$	Output current (continuos)	Internally limited	A
$I_R$	Reverse output current (per channel)	-5	A
$I_{IN}$	Input current (per channel)	$\pm 10$	mA
$V_{IN}$	Input voltage	$+V_{CC}$	V
$V_{STAT}$	Status pin voltage	$+V_{CC}$	V
$I_{STAT}$	Status pin current	$\pm 10$	mA
$V_{ESD}$	Electrostatic discharge ( $R = 1.5 \text{ k}\Omega$ ; $C = 100 \text{ pF}$ )	2000	V
$E_{AS}$	Single pulse avalanche energy per channel not simultaneous	300	mJ
$P_{TOT}$	Power dissipation at $T_c = 25^\circ\text{C}$	Internally limited	W
$T_J$	Junction operating temperature	Internally limited	$^\circ\text{C}$
$T_{STG}$	Storage temperature	-55 to 150	$^\circ\text{C}$

## 2.1 Thermal data

**Table 3. Thermal data**

Symbol	Parameter	Value	Unit
$R_{th(JC)}$	Thermal resistance junction-case <sup>(1)</sup>	Max.	$2 \text{ } ^\circ\text{C/W}$
$R_{th(JA)}$	Thermal resistance junction-ambient	Max.	see <a href="#">Figure 11</a> $^\circ\text{C/W}$

1. Per channel.

## 3 Recommended

**Table 4. Input switching limits**

Symbol	Parameter	Value	Unit
$f_{Vin \text{ MAX}}$	Maximum input switching frequency	10	kHz

## 4 Electrical characteristics

$10.5 \text{ V} < V_{CC} < 36 \text{ V}$ ;  $-40^\circ\text{C} < T_J < 125^\circ\text{C}$ ; unless otherwise specified.

**Table 5. Power section**

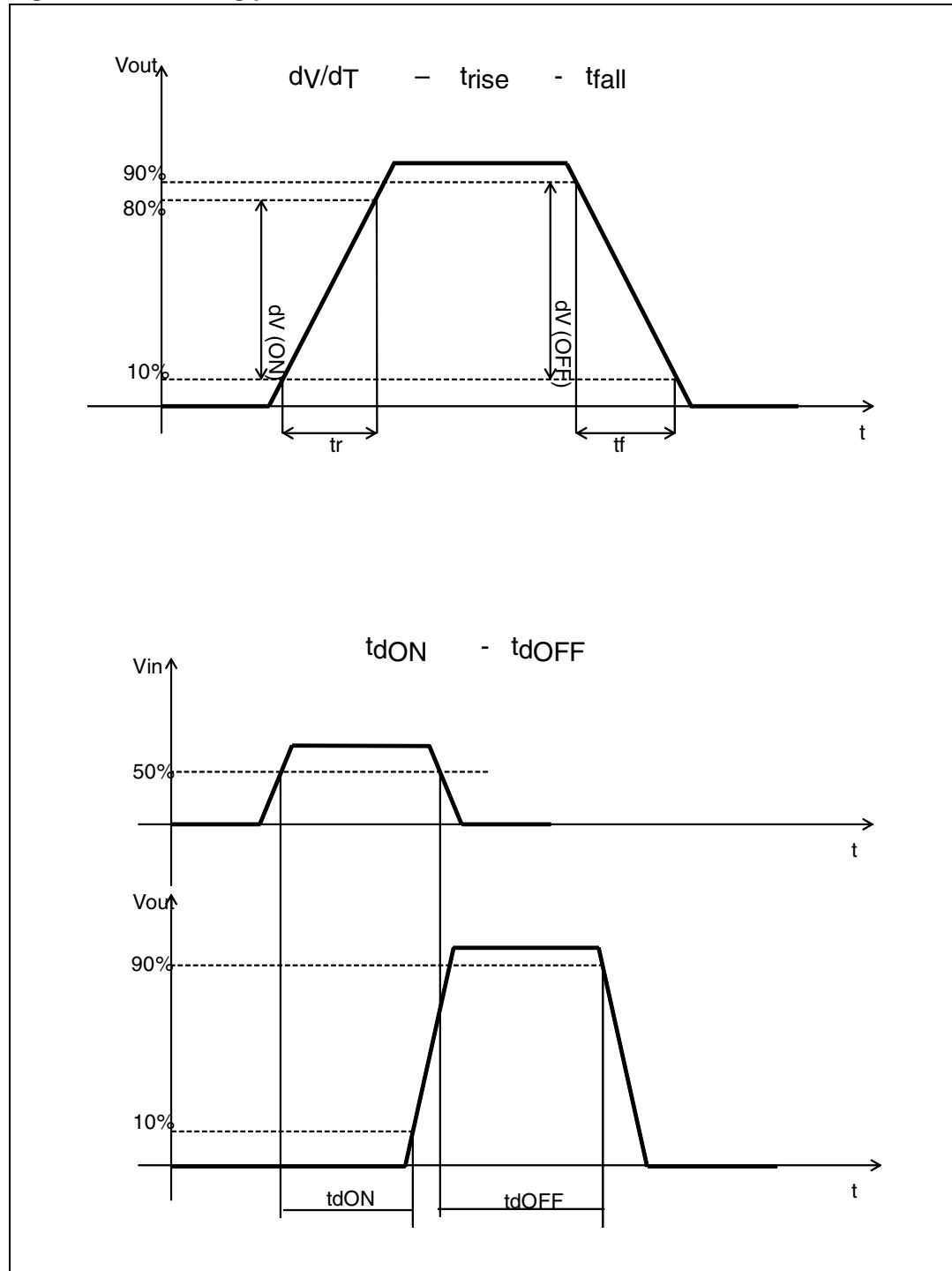
Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
$V_{CC}$	Supply voltage		10.5		36	V
$R_{DS(ON)}$	ON state resistance	$I_{OUT} = 0.7 \text{ A}$ at $T_J = 25^\circ\text{C}$ $I_{OUT} = 0.7 \text{ A}$			0.080 0.140	$\Omega$ $\Omega$
$V_{clamp}$		$I_s = 20 \text{ mA}$	41	45	52	V
$I_s$	Supply current	All channels in OFF state, ON state with $V_{IN} = 5 \text{ V}$		250 2.4	4	$\mu\text{A}$ mA
$V_{OUT(OFF)}$	OFF state output voltage	$V_{IN} = 0 \text{ V}$ and $I_{OUT} = 0 \text{ A}$			1	V
$I_{OUT(OFF)}$	OFF state output current	$V_{IN} = V_{OUT} = 0 \text{ V}$	0		5	$\mu\text{A}$
$I_{LGND}$	Output current in ground disconnection	$V_{cc} = V_{IN} = GND = 24 \text{ V}$ ; $T_J = 125^\circ\text{C}$			500	$\mu\text{A}$
$F_{CP}$	Charge pump frequency	Channel in ON state <sup>(1)</sup>		1450		kHz

1. To cover EN55022 class A and class B normative.

$V_{CC} = 24 \text{ V}$ ;  $-25^\circ\text{C} < T_J < 125^\circ\text{C}$ ,  $R_L = 48 \Omega$ , input rise time  $< 0.1 \mu\text{s}$ )

**Table 6. Switching**

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
$t_d(ON)$	Turn ON delay			6		$\mu\text{s}$
$t_r$	Rise time			5		$\mu\text{s}$
$t_d(OFF)$	Turn OFF			12		$\mu\text{s}$
$t_f$	Fall time			5		$\mu\text{s}$
$dV/dt(ON)$	Turn ON voltage slope			4		$\text{V}/\mu\text{s}$
$dV/dt(off)$	Turn OFF voltage slope			4		$\text{V}/\mu\text{s}$

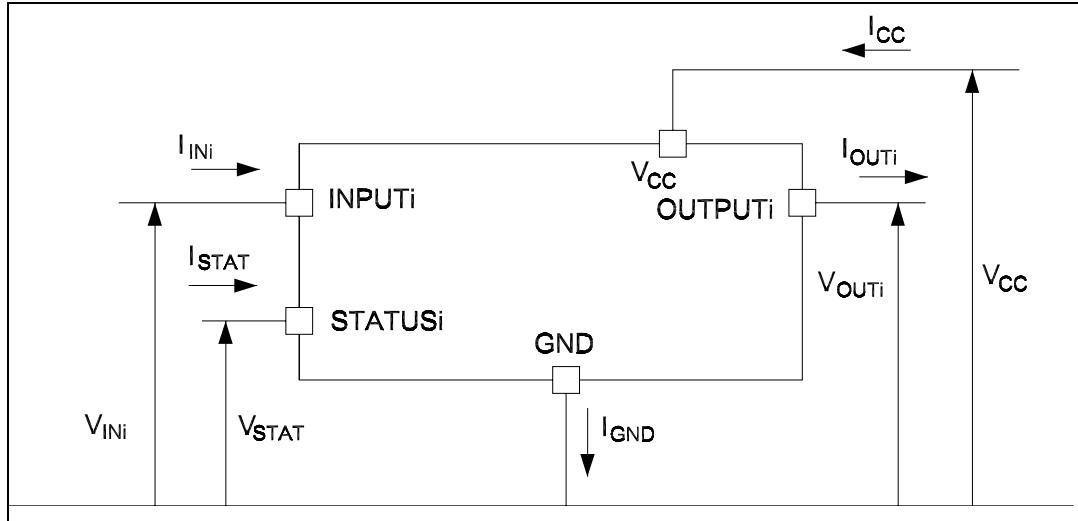
**Figure 3. Switching parameter conventions**

**Table 7. Logical input**

<b>Symbol</b>	<b>Parameter</b>	<b>Test conditions</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
$V_{IL}$	Input low level voltage				0.8	V
$V_{IH}$	Input high level voltage		2.20			V
$V_{I(HYST)}$	Input hysteresis voltage			0.15		V
$I_{IN}$	Input current	$V_{IN} = 15 \text{ V}$			10	$\mu\text{A}$
		$V_{IN} = 36 \text{ V}$			210	

**Table 8. Protection and diagnostic**

<b>Symbol</b>	<b>Parameter</b>	<b>Test conditions</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
$V_{STAT}$	Status voltage output low	$I_{STAT} = 1.6 \text{ mA}$			0.6	V
$V_{USD}$	Undervoltage protection		7		10.5	V
$V_{USDHYS}$	Undervoltage hysteresis		0.4	0.5		V
$I_{LIM}$	DC short-circuit current	$V_{CC} = 24 \text{ V}; R_{LOAD} < 10 \text{ m}\Omega$	1.01		2.6	A
$I_{PEAK}$	Maximum DC output current	Dynamic load		1.6		A
$I_{LSTAT}$	Status leakage current	$V_{CC} = V_{STAT} = 36 \text{ V}$		30		$\mu\text{A}$
$T_{TSD}$	Junction shutdown temperature		150	170	190	$^{\circ}\text{C}$
$T_R$	Junction reset temperature		135			$^{\circ}\text{C}$
$T_{THIST}$	Junction thermal hysteresis		7	15		$^{\circ}\text{C}$
$T_{CSD}$	Case shutdown temperature		125	130	135	$^{\circ}\text{C}$
$T_{CR}$	Case reset temperature		110			$^{\circ}\text{C}$
$T_{CHYST}$	Case thermal hysteresis		7	15		$^{\circ}\text{C}$
$V_{demag}$	Output voltage at turn-OFF	$I_{OUT} = 0.5 \text{ A}; L_{LOAD} \geq 1 \text{ mH}$	$V_{CC^-41}$	$V_{CC^-45}$	$V_{CC^-52}$	V

**Figure 4. Current and voltage conventions**

## 5 Truth table

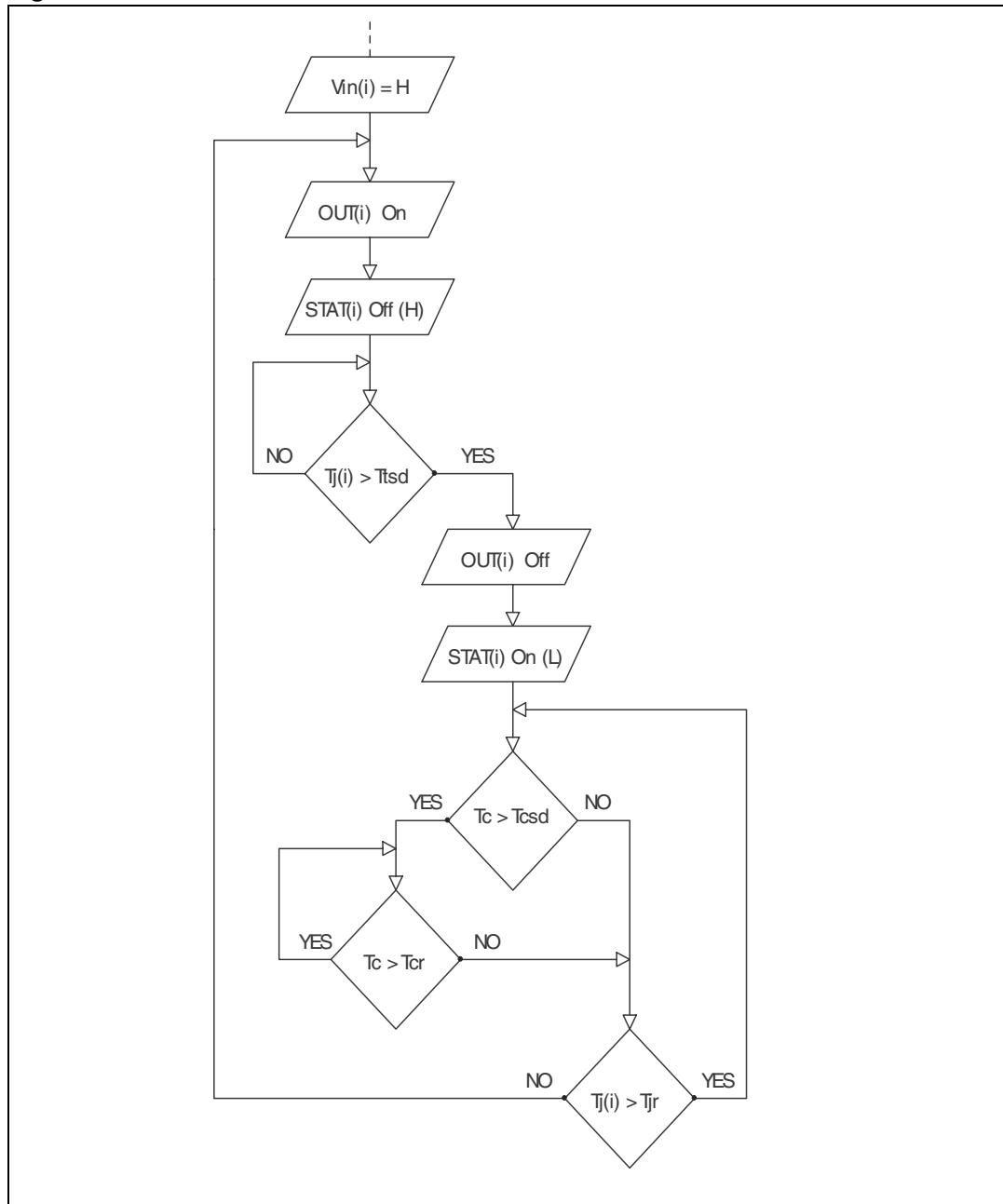
**Table 9. Truth table**

Conditions	INPUTn	OUTPUTn	STATUSn
Normal operation	L	L	H
	H	H	H
Overtemperature	L	L	H
	H	L	L
Undervoltage	L	L	X
	H	L	X
Shorted load (Current limitation before thermal shutdown)	L	L	H
	H	X	H

## 6 Thermal management

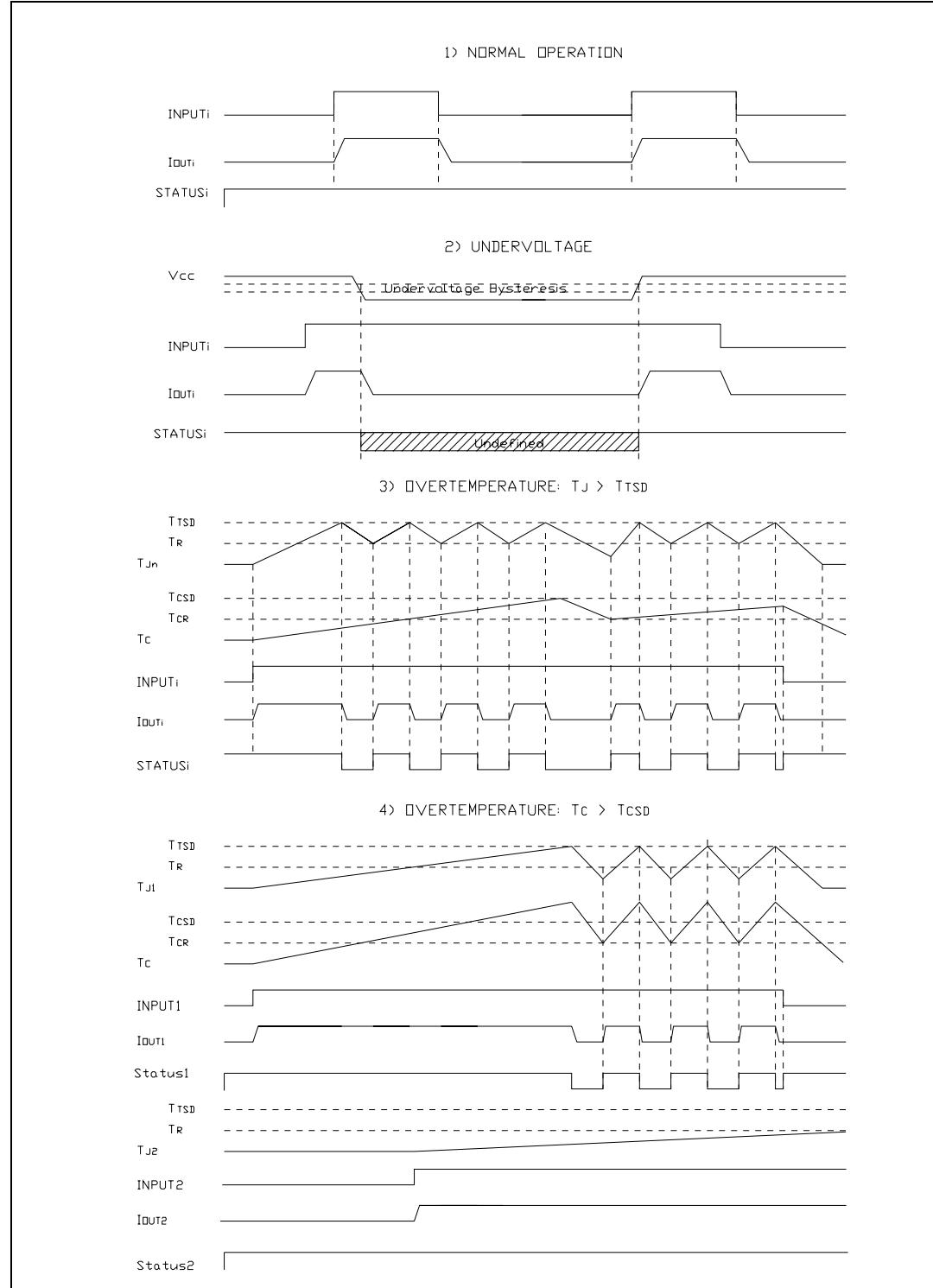
The power dissipation in the IC is the main factor that sets the safe operating condition of the device in the application. Therefore, it must be very carefully considered. Furthermore, the available space on the PCB should be chosen considering the power dissipation. Heatsinking can be achieved using copper on the PCB with proper area and thickness. Two different protections have been implemented to guarantee safety of the device if it overheats due to an overloaded condition or high environment temperature. The following flowchart explains in detail this protection functionality.

**Figure 5. Thermal behavior**



## 7 Switching waveforms

**Figure 6. Switching waveforms**



## 8 Pin functions

Figure 7. Input circuit

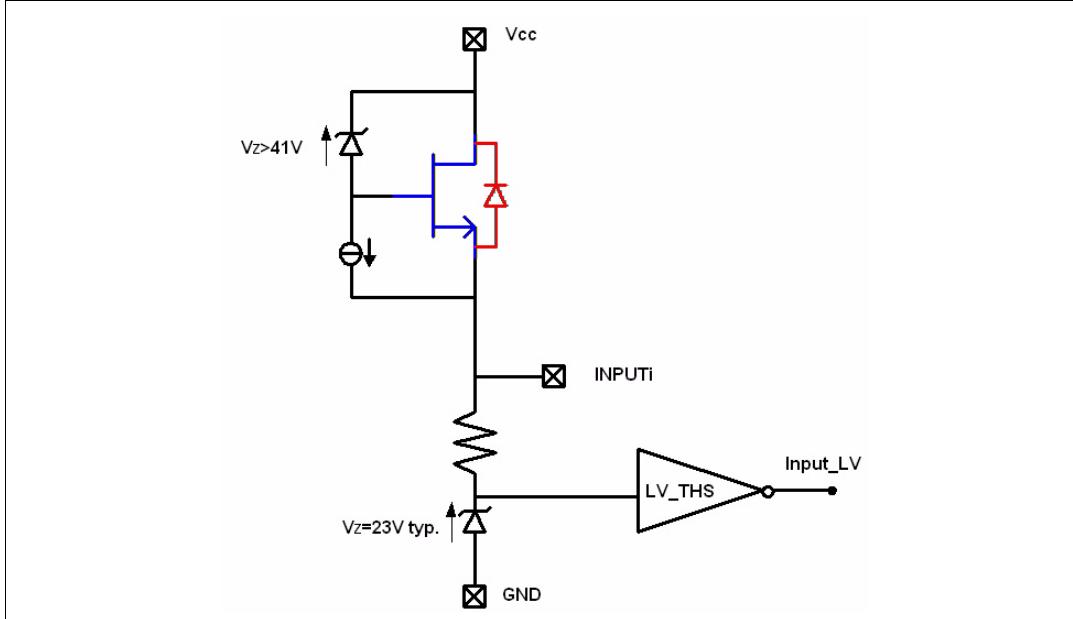
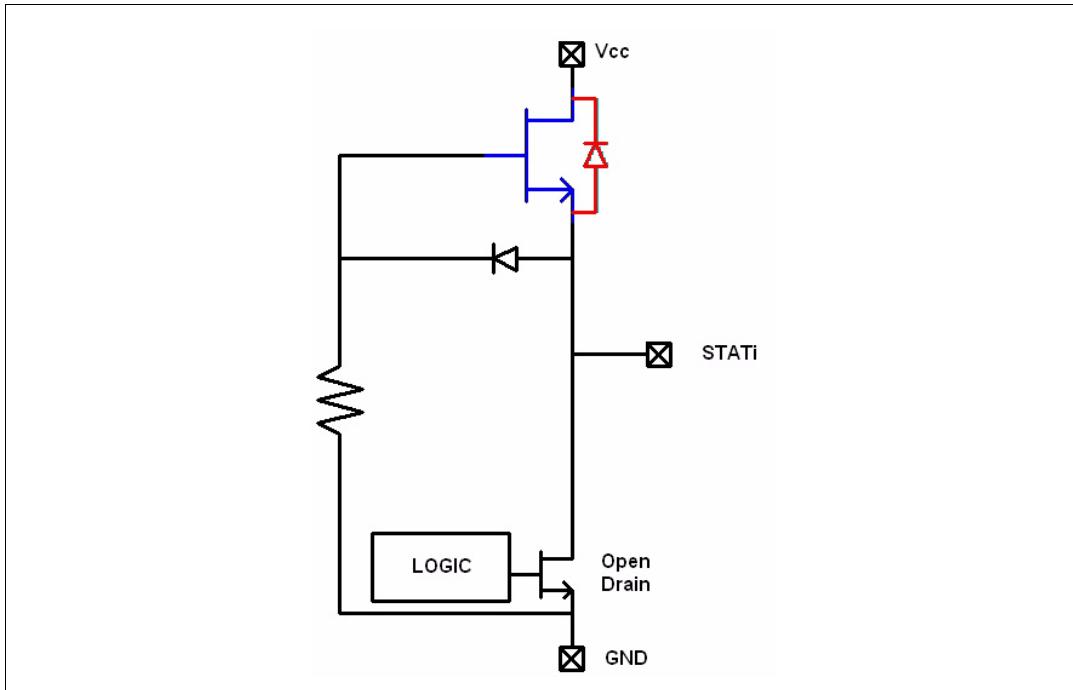
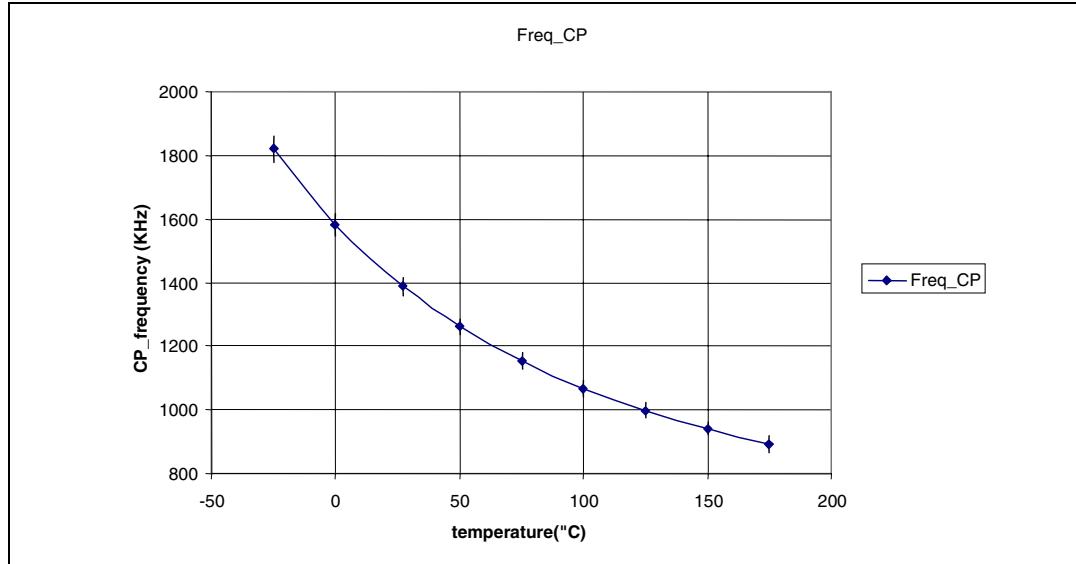


Figure 8. Status circuit

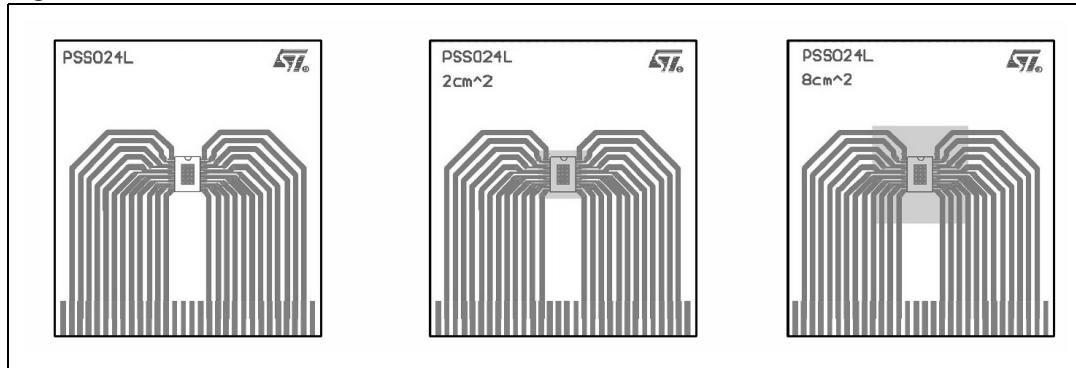


**Figure 9. Charge pump switching frequency (typical) vs. temperature**

## 9 Package and PCB thermal data

### 9.1 VNI4140K-32 thermal data

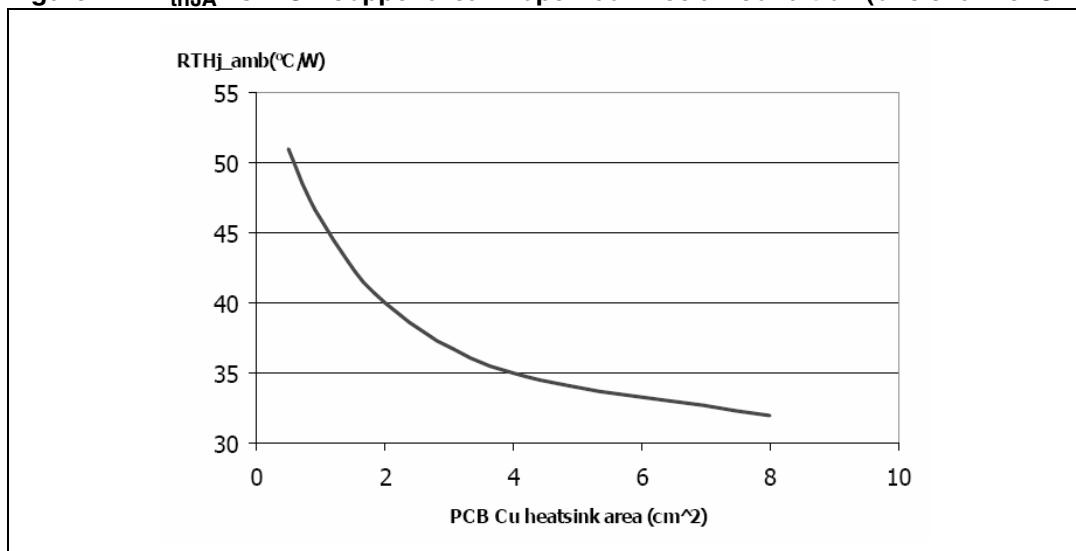
Figure 10. VNI4140K-32 PCB



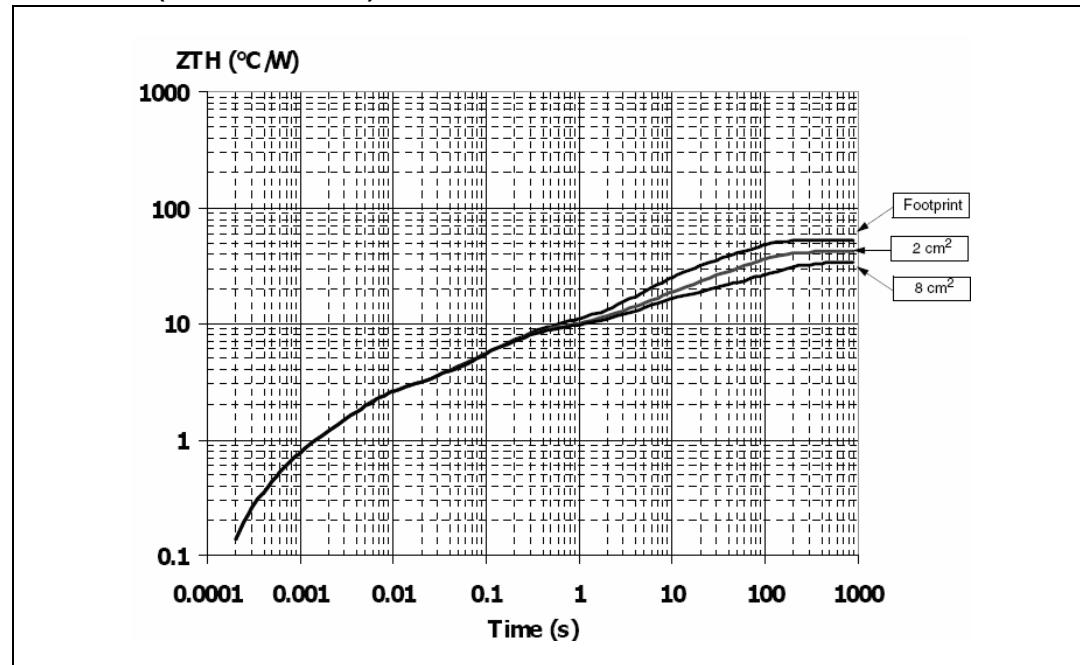
Note:

Layout condition of  $R_{th}$  and  $Z_{th}$  measurements (PCB: Double layer, Thermal Vias, FR4 area = 77 mm x 86 mm, PCB thickness=1.6 mm, Cu thickness = 70 µm (front and back side), Copper areas: from minimum pad layout to 8 cm<sup>2</sup>).

Figure 11.  $R_{thJA}$  vs. PCB copper area in open box free air condition (one channel ON)



**Figure 12.** VNI4140K-32 thermal impedance junction ambient single pulse  
(one channel ON)



## 10 Reverse polarity protection

This schematic can be used with any type of load.

The following is an indication on how to dimension the  $R_{GND}$  resistor.

$$R_{GND} = (-V_{CC}) / (-I_{GND})$$

where  $-I_{GND}$  is the DC reverse ground pin current and can be found in the absolute maximum rating section of the device datasheet.

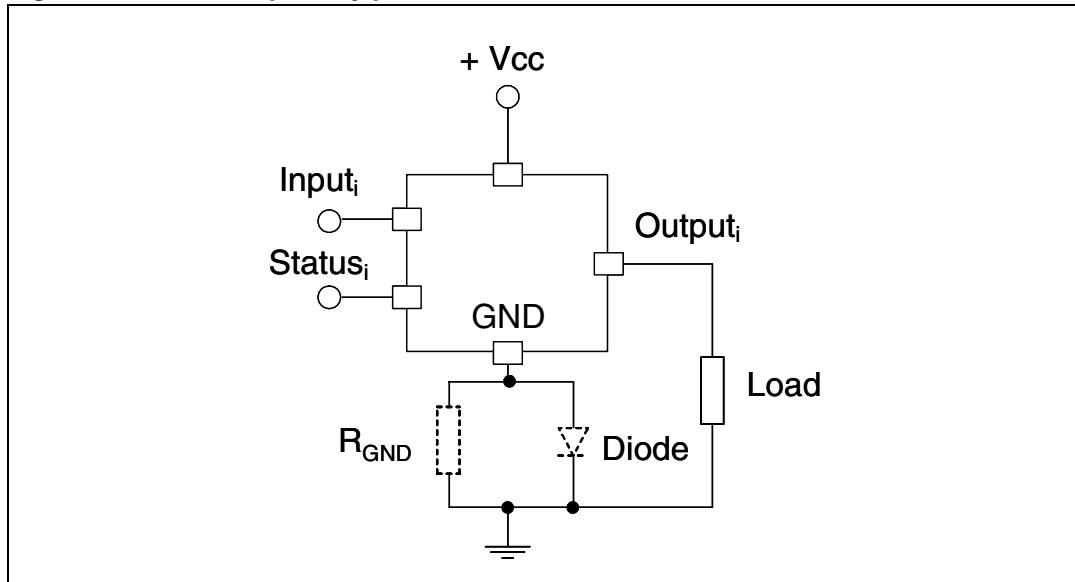
Power dissipation in  $R_{GND}$  (when  $V_{CC} < 0$ : during reverse polarity situations) is:

$$PD = (-V_{CC})^2 / R_{GND}$$

*Note:*

*In normal conditions (no reverse polarity) due to the diode there is a voltage drop between GND of the device and GND of the system.*

**Figure 13. Reverse polarity protection**

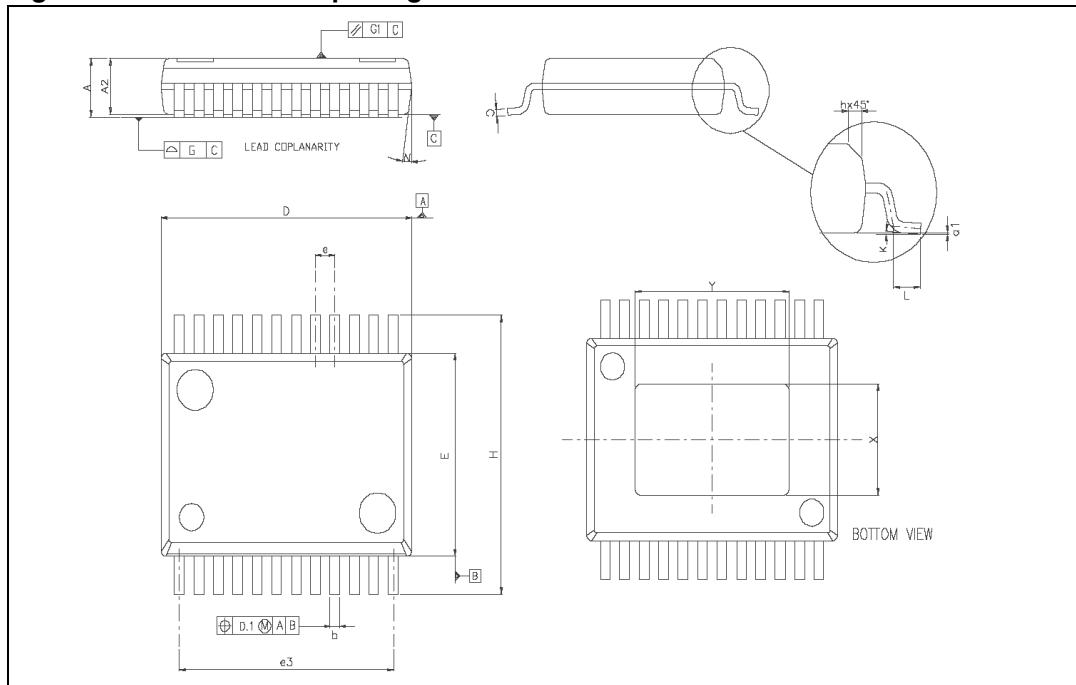


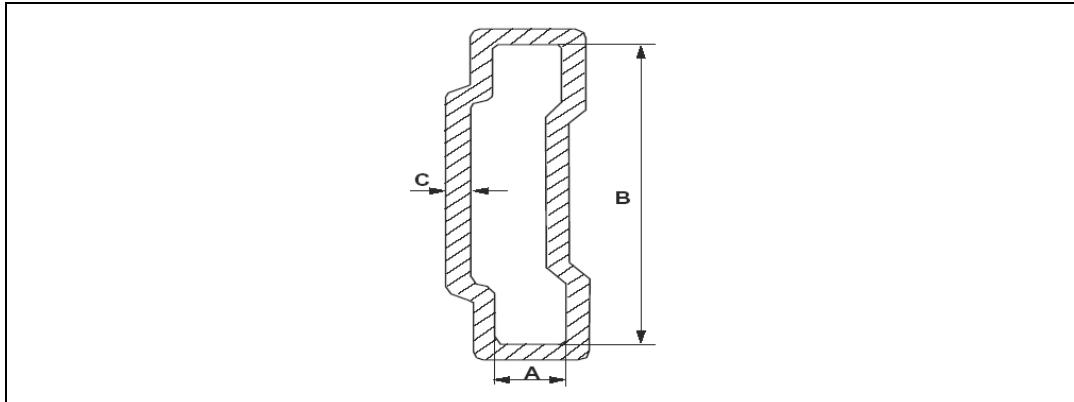
## 11 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).  
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**Table 10. PowerSSO-24 mechanical data**

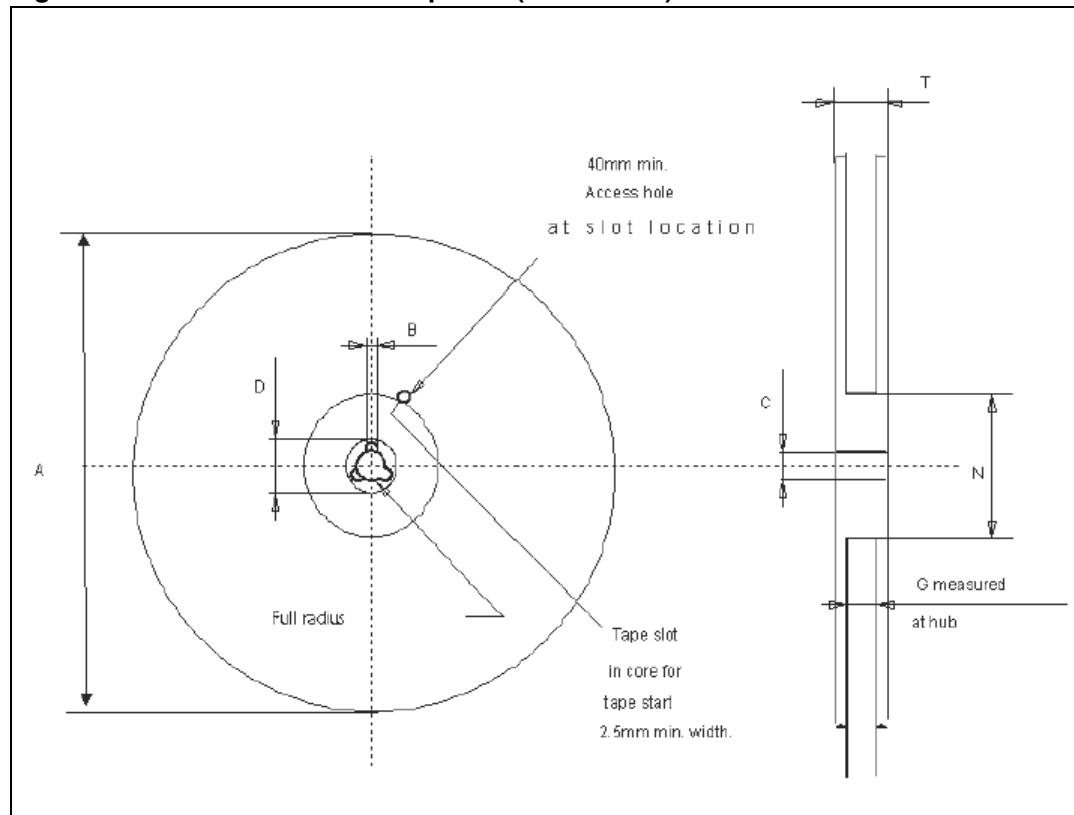
Symbol	mm		
	Min.	Typ.	Max.
A	2.15		2.47
A2	2.15		2.40
a1	0		0.075
b	0.33		0.51
c	0.23		0.32
D	10.10		10.50
E	7.4		7.6
e		0.8	
e3		8.8	
G			0.1
G1			0.06
H	10.1		10.5
h			0.4
L	0.55		0.85
N			10deg
X	4.1		4.7
Y	6.5		7.1

**Figure 14. PowerSSO-24 package dimensions**

**Figure 15. PowerSSO-24 tube shipment (no suffix)****Table 11. PowerSSO-24 tube shipment**

<b>Base Q.ty</b>	49
<b>Bulk Q.ty</b>	1225
<b>Tube length (<math>\pm 0.5</math>)</b>	532
<b>A</b>	3.5
<b>B</b>	13.8
<b>C (<math>\pm 0.1</math>)</b>	0.6

*Note:* All dimensions are in mm.

**Figure 16.** PowerSSO-24 reel shipment (suffix "TR")**Table 12.** PowerSSO-24 reel dimensions

<b>Base Q.ty</b>	1000
<b>Bulk Q.ty</b>	1000
<b>A (max.)</b>	330
<b>B (min.)</b>	1.5
<b>C (<math>\pm 0.2</math>)</b>	13
<b>F</b>	20.2
<b>G (<math>2 \pm 0</math>)</b>	24.4
<b>N (min.)</b>	100
<b>T (max.)</b>	30.4

Figure 17. PowerSSO-24 tape dimensions

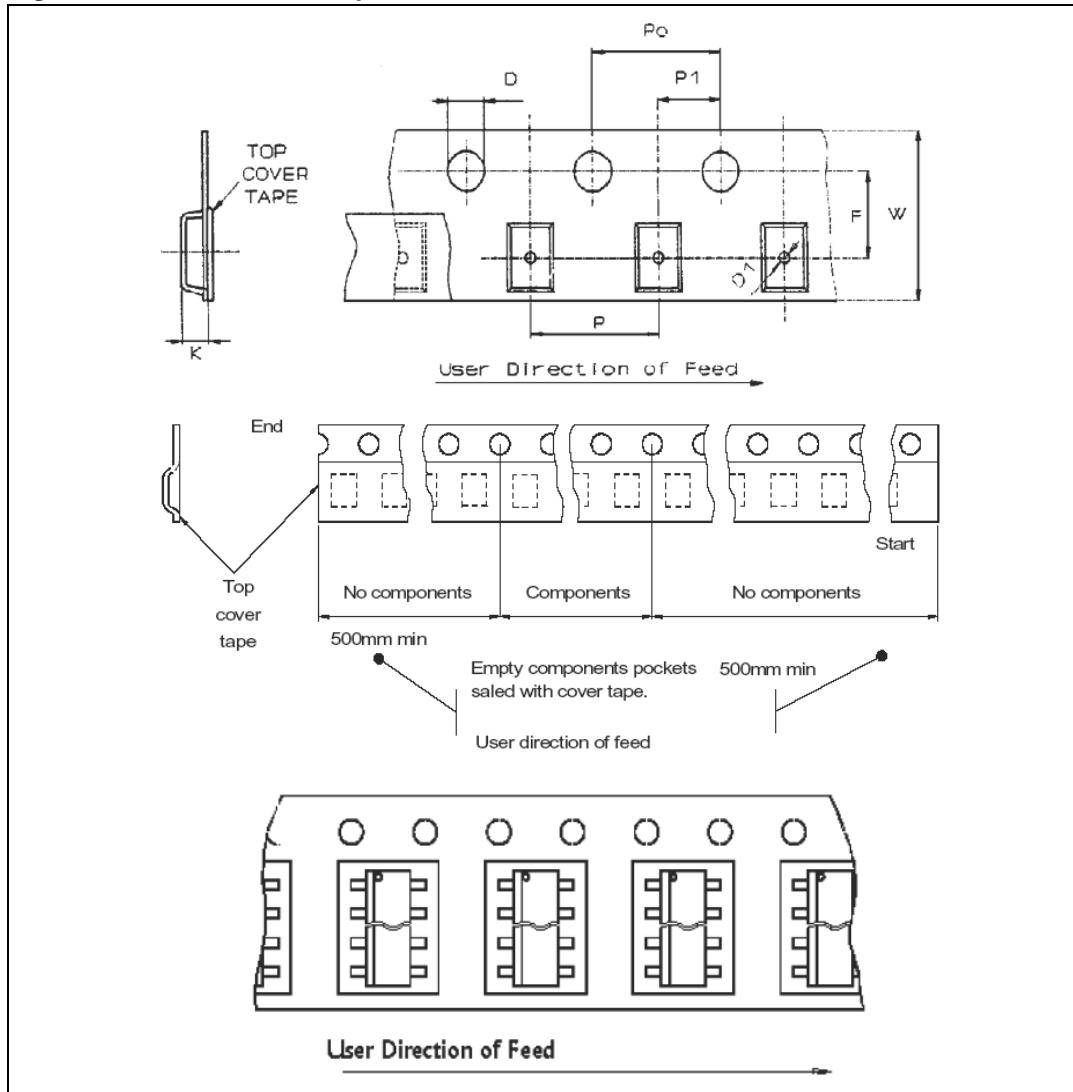
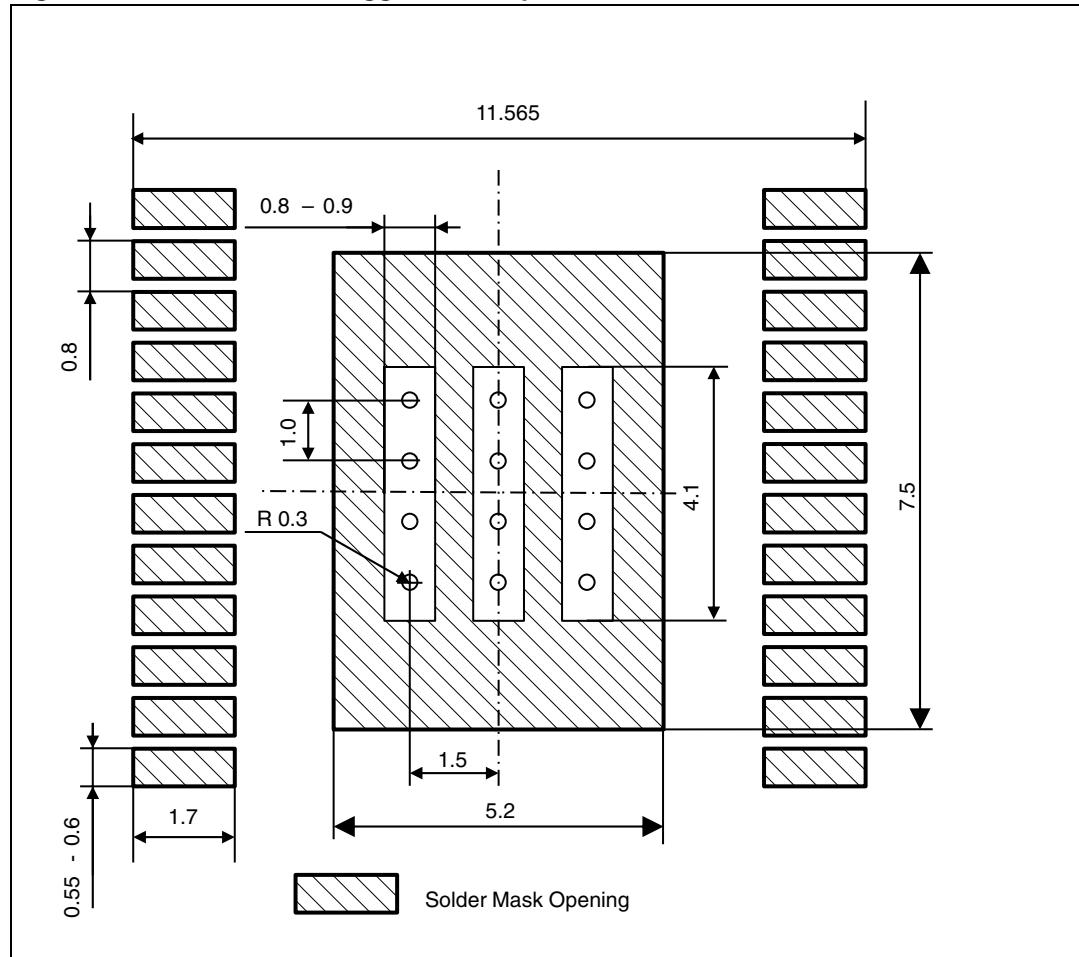


Table 13. PowerSSO-24 tape dimensions

<b>Tape width</b>	<b>W</b>	<b>24</b>
<b>Tape Hole Spacing</b>	<b>P0 (<math>\pm 0.1</math>)</b>	<b>4</b>
<b>Component Spacing</b>	<b>P</b>	<b>12</b>
<b>Hole Diameter</b>	<b>D (<math>\pm 0.05</math>)</b>	<b>1.55</b>
<b>Hole Diameter</b>	<b>D1 (min)</b>	<b>1.5</b>
<b>Hole Position</b>	<b>F (<math>\pm 0.1</math>)</b>	<b>11.5</b>
<b>Compartment Depth</b>	<b>K (max)</b>	<b>2.85</b>
<b>Hole Spacing</b>	<b>P1 (<math>\pm 0.1</math>)</b>	<b>2</b>

Note: According to the electronic industries association (EIA) standard 481 rev. A, Feb 1986.

**Figure 18.** VNI4140K-32 suggested footprint

Note:

*STMicroelectronics is not responsible for any PCB related issues. The footprint shown in the above figure is a suggestion which might not be in line to the customer PCB supplier design rules.*

*All dimensions are in mm.*

## 12 Ordering information

**Table 14. Ordering information**

Order codes	Package	Packaging
VNI4140K-32	PowerSSO-24	Tube
VNI4140KTR-32	PowerSSO-24	Tape and reel

## 13 Revision history

**Table 15. Document revision history**

Date	Revision	Changes
12-Dec-2011	1	Initial release.
06-Feb-2012	2	Updated $I_{lim}$ minimum value in <a href="#">Table 8: Protection and diagnostic</a> . Inserted new feature: ESD according to IEC 61000-4-2 up to +/-25 KV, in cover page.
07-Mar-2012	3	Suggested footprint inserted. In <a href="#">Table 5</a> , parameter $I_{LGND}$ has been added.

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